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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	e200z0h
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, I²C, LINbus, SCI, SPI
Peripherals	DMA, POR, PWM, WDT
Number of I/O	123
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	64K x 8
RAM Size	24K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 36x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-LQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5602bk0clq4r

1 Feature set dependent on selected peripheral multiplexing—table shows example implementation
2 Based on 125 °C ambient operating temperature
3 See the eMIOS section of the device reference manual for information on the channel configuration and functions.
4 IC – Input Capture; OC – Output Compare; PWM – Pulse Width Modulation; MC – Modulus counter
5 SCI0, SCI1 and SCI2 are available. SCI3 is not available.
6 CAN0, CAN1 are available. CAN2, CAN3, CAN4 and CAN5 are not available.
7 CAN0, CAN1 and CAN2 are available. CAN3, CAN4 and CAN5 are not available.
8 I/O count based on multiplexing with peripherals
9 208 MAPBGA available only as development package for Nexus2+

Table 2. MPC5604B/C device comparison[1]

Feature	Device										
	SPC560B 40L1	**SPC560B 40L3**	**SPC560B 40L5**	**SPC560C 40L1**	**SPC560C 40L3**	**SPC560B 50L1**	**SPC560B 50L3**	**SPC560B 50L5**	**SPC560C 50L1**	**SPC560C 50L3**	**SPC560B 50B2**
CPU	e200z0h										
Execution speed[2]	Static – up to 64 MHz										
Code Flash	256 KB					512 KB					
Data Flash	64 KB (4 × 16 KB)										
RAM	24 KB			32 KB		32 KB			48 KB		
MPU	8-entry										
ADC (10-bit)	12 ch	28 ch	36 ch	8 ch	28 ch	12 ch	28 ch	36 ch	8 ch	28 ch	36 ch
CTU	Yes										
Total timer I/O[3] eMIOS	12 ch, 16-bit	28 ch, 16-bit	56 ch, 16-bit	12 ch, 16-bit	28 ch, 16-bit	12 ch, 16-bit	28 ch, 16-bit	56 ch, 16-bit	12 ch, 16-bit	28 ch, 16-bit	56 ch, 16-bit
• PWM + MC + IC/OC[4]	2 ch	5 ch	10 ch	2 ch	5 ch	2 ch	5 ch	10 ch	2 ch	5 ch	10 ch
• PWM + IC/OC[4]	10 ch	20 ch	40 ch	10 ch	20 ch	10 ch	20 ch	40 ch	10 ch	20 ch	40 ch
• IC/OC[4]	—	3 ch	6 ch	—	3 ch	—	3 ch	6 ch	—	3 ch	6 ch
SCI (LINFlex)	3[5]			4							
SPI (DSPI)	2	3		2	3	2	3		2	3	
CAN (FlexCAN)	2[6]			5	6	3[7]			5	6	
I^2C	1										
32 kHz oscillator	Yes										
GPIO[8]	45	79	123	45	79	45	79	123	45	79	123
Debug	JTAG										Nexus2+
Package	LQFP64[9]	LQFP100	LQFP144	LQFP64[9]	LQFP100	LQFP64[9]	LQFP100	LQFP144	LQFP64[9]	LQFP100	LBGA208[10]

1 Feature set dependent on selected peripheral multiplexing—table shows example implementation

2 Based on 125 °C ambient operating temperature

3 See the eMIOS section of the device reference manual for information on the channel configuration and functions.

4 IC – Input Capture; OC – Output Compare; PWM – Pulse Width Modulation; MC – Modulus counter

5 SCI0, SCI1 and SCI2 are available. SCI3 is not available.

[6] CAN0, CAN1 are available. CAN2, CAN3, CAN4 and CAN5 are not available.
[7] CAN0, CAN1 and CAN2 are available. CAN3, CAN4 and CAN5 are not available.
[8] I/O count based on multiplexing with peripherals
[9] All LQFP64information is indicative and must be confirmed during silicon validation.
[10] LBGA208 available only as development package for Nexus2+

Table 3 summarizes the functions of all blocks present in the MPC5604B/C series of microcontrollers. Please note that the presence and number of blocks vary by device and package.

Table 3. MPC5604B/C series block summary

Block	Function
Analog-to-digital converter (ADC)	Multi-channel, 10-bit analog-to-digital converter
Boot assist module (BAM)	A block of read-only memory containing VLE code which is executed according to the boot mode of the device
Clock monitor unit (CMU)	Monitors clock source (internal and external) integrity
Cross triggering unit (CTU)	Enables synchronization of ADC conversions with a timer event from the eMIOS or from the PIT
Deserial serial peripheral interface (DSPI)	Provides a synchronous serial interface for communication with external devices
Error Correction Status Module (ECSM)	Provides a myriad of miscellaneous control functions for the device including program-visible information about configuration and revision levels, a reset status register, wakeup control for exiting sleep modes, and optional features such as information on memory errors reported by error-correcting codes
Enhanced Direct Memory Access (eDMA)	Performs complex data transfers with minimal intervention from a host processor via "*n*" programmable channels.
Enhanced modular input output system (eMIOS)	Provides the functionality to generate or measure events
Flash memory	Provides non-volatile storage for program code, constants and variables
FlexCAN (controller area network)	Supports the standard CAN communications protocol
Frequency-modulated phase-locked loop (FMPLL)	Generates high-speed system clocks and supports programmable frequency modulation
Internal multiplexer (IMUX) SIU subblock	Allows flexible mapping of peripheral interface on the different pins of the device
Inter-integrated circuit (I^2C™) bus	A two wire bidirectional serial bus that provides a simple and efficient method of data exchange between devices
Interrupt controller (INTC)	Provides priority-based preemptive scheduling of interrupt requests
JTAG controller	Provides the means to test chip functionality and connectivity while remaining transparent to system logic when not in test mode
LINFlex controller	Manages a high number of LIN (Local Interconnect Network protocol) messages efficiently with a minimum of CPU load
Clock generation module (MC_CGM)	Provides logic and control required for the generation of system and peripheral clocks
Mode entry module (MC_ME)	Provides a mechanism for controlling the device operational mode and mode transition sequences in all functional states; also manages the power control unit, reset generation module and clock generation module, and holds the configuration, control and status registers accessible for applications
Power control unit (MC_PCU)	Reduces the overall power consumption by disconnecting parts of the device from the power supply via a power switching device; device components are grouped into sections called "power domains" which are controlled by the PCU
Reset generation module (MC_RGM)	Centralizes reset sources and manages the device reset sequence of the device

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PC[2]	PCR[34]	AF0 AF1 AF2 AF3 —	GPIO[34] SCK_1 CAN4TX[11] — EIRQ[5]	SIUL DSPI_1 FlexCAN_4 — SIUL	I/O I/O O — I	M	Tristate	50	50	78	117	A11
PC[3]	PCR[35]	AF0 AF1 AF2 AF3 — — —	GPIO[35] CS0_1 MA[0] — CAN1RX CAN4RX[11] EIRQ[6]	SIUL DSPI_1 ADC — FlexCAN_1 FlexCAN_4 SIUL	I/O I/O O — I I I	S	Tristate	49	49	77	116	B11
PC[4]	PCR[36]	AF0 AF1 AF2 AF3 — —	GPIO[36] — — — SIN_1 CAN3RX[11]	SIUL — — — DSPI_1 FlexCAN_3	I/O — — — I I	M	Tristate	62	62	92	131	B7
PC[5]	PCR[37]	AF0 AF1 AF2 AF3 —	GPIO[37] SOUT_1 CAN3TX[11] — EIRQ[7]	SIUL DSPI1 FlexCAN_3 — SIUL	I/O O O — I	M	Tristate	61	61	91	130	A7
PC[6]	PCR[38]	AF0 AF1 AF2 AF3	GPIO[38] LIN1TX — —	SIUL LINFlex_1 — —	I/O O — —	S	Tristate	16	16	25	36	R2
PC[7]	PCR[39]	AF0 AF1 AF2 AF3 — —	GPIO[39] — — — LIN1RX WKPU[12][4]	SIUL — — — LINFlex_1 WKPU	I/O — — — I I	S	Tristate	17	17	26	37	P3
PC[8]	PCR[40]	AF0 AF1 AF2 AF3	GPIO[40] LIN2TX — —	SIUL LINFlex_2 — —	I/O O — —	S	Tristate	63	63	99	143	A1

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PD[1]	PCR[49]	AF0 AF1 AF2 AF3 —	GPIO[49] — — — GPI[5]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	42	64	T12
PD[2]	PCR[50]	AF0 AF1 AF2 AF3 —	GPIO[50] — — — GPI[6]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	43	65	R12
PD[3]	PCR[51]	AF0 AF1 AF2 AF3 —	GPIO[51] — — — GPI[7]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	44	66	P13
PD[4]	PCR[52]	AF0 AF1 AF2 AF3 —	GPIO[52] — — — GPI[8]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	45	67	R13
PD[5]	PCR[53]	AF0 AF1 AF2 AF3 —	GPIO[53] — — — GPI[9]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	46	68	T13
PD[6]	PCR[54]	AF0 AF1 AF2 AF3 —	GPIO[54] — — — GPI[10]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	47	69	T14
PD[7]	PCR[55]	AF0 AF1 AF2 AF3 —	GPIO[55] — — — GPI[11]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	48	70	R14
PD[8]	PCR[56]	AF0 AF1 AF2 AF3 —	GPIO[56] — — — GPI[12]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	49	71	T15

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PE[10]	PCR[74]	AF0 AF1 AF2 AF3 —	GPIO[74] LIN3TX CS3_1 — EIRQ[10]	SIUL LINFlex_3 DSPI_1 — SIUL	I/O O O — I	S	Tristate	—	—	11	15	G3
PE[11]	PCR[75]	AF0 AF1 AF2 AF3 — —	GPIO[75] — CS4_1 — LIN3RX WKPU[14][4]	SIUL — DSPI_1 — LINFlex_3 WKPU	I/O — O — I I	S	Tristate	—	—	13	17	H2
PE[12]	PCR[76]	AF0 AF1 AF2 AF3 — —	GPIO[76] — E1UC[19][13] — SIN_2 EIRQ[11]	SIUL — eMIOS_1 — DSPI_2 SIUL	I/O — I/O — I I	S	Tristate	—	—	76	109	C14
PE[13]	PCR[77]	AF0 AF1 AF2 AF3	GPIO[77] SOUT2 E1UC[20] —	SIUL DSPI_2 eMIOS_1 —	I/O O I/O —	S	Tristate	—	—	—	103	D15
PE[14]	PCR[78]	AF0 AF1 AF2 AF3 —	GPIO[78] SCK_2 E1UC[21] — EIRQ[12]	SIUL DSPI_2 eMIOS_1 — SIUL	I/O I/O I/O — I	S	Tristate	—	—	—	112	C13
PE[15]	PCR[79]	AF0 AF1 AF2 AF3	GPIO[79] CS0_2 E1UC[22] —	SIUL DSPI_2 eMIOS_1 —	I/O I/O I/O —	M	Tristate	—	—	—	113	A13
PF[0]	PCR[80]	AF0 AF1 AF2 AF3 —	GPIO[80] E0UC[10] CS3_1 — ANS[8]	SIUL eMIOS_0 DSPI_1 — ADC	I/O I/O O — I	J	Tristate	—	—	—	55	N10
PF[1]	PCR[81]	AF0 AF1 AF2 AF3 —	GPIO[81] E0UC[11] CS4_1 — ANS[9]	SIUL eMIOS_0 DSPI_1 — I	I/O I/O O — I	J	Tristate	—	—	—	56	P10

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PF[10]	PCR[90]	AF0 AF1 AF2 AF3	GPIO[90] — — —	SIUL — — —	I/O — — —	M	Tristate	—	—	—	38	R3
PF[11]	PCR[91]	AF0 AF1 AF2 AF3 —	GPIO[91] — — — WKPU[15][4]	SIUL — — — WKPU	I/O — — — I	S	Tristate	—	—	—	39	R4
PF[12]	PCR[92]	AF0 AF1 AF2 AF3	GPIO[92] E1UC[25] — —	SIUL eMIOS_1 — —	I/O I/O — —	M	Tristate	—	—	—	35	R1
PF[13]	PCR[93]	AF0 AF1 AF2 AF3 —	GPIO[93] E1UC[26] — — WKPU[16][4]	SIUL eMIOS_1 — — WKPU	I/O I/O — — I	S	Tristate	—	—	—	41	T6
PF[14]	PCR[94]	AF0 AF1 AF2 AF3	GPIO[94] CAN4TX[11] E1UC[27] CAN1TX	SIUL FlexCAN_4 eMIOS_1 FlexCAN_4	I/O O I/O O	M	Tristate	—	43	—	102	D14
PF[15]	PCR[95]	AF0 AF1 AF2 AF3 — — —	GPIO[95] — — — CAN1RX CAN4RX[11] EIRQ[13]	SIUL — — — FlexCAN_1 FlexCAN_4 SIUL	I/O — — — I I I	S	Tristate	—	42	—	101	E15
PG[0]	PCR[96]	AF0 AF1 AF2 AF3	GPIO[96] CAN5TX[11] E1UC[23] —	SIUL FlexCAN_5 eMIOS_1 —	I/O O I/O —	M	Tristate	—	41	—	98	E14
PG[1]	PCR[97]	AF0 AF1 AF2 AF3 — —	GPIO[97] — E1UC[24] — CAN5RX[11] EIRQ[14]	SIUL — eMIOS_1 — FlexCAN_5 SIUL	I/O — I/O — I I	S	Tristate	—	40	—	97	E13

3.14 Thermal characteristics

3.14.1 Package thermal characteristics

Table 15. LQFP thermal characteristics[1]

Symbol		C	Parameter	Conditions[2]	Pin count	Value	Unit
$R_{\theta JA}$	CC	D	Thermal resistance, junction-to-ambient natural convection[3]	Single-layer board - 1s	64	60	°C/W
					100	64	
					144	64	
				Four-layer board - 2s2p	64	42	
					100	51	
					144	49	
$R_{\theta JB}$	CC	D	Thermal resistance, junction-to-board[4]	Single-layer board - 1s	64	24	°C/W
					100	36	
					144	37	
				Four-layer board - 2s2p	64	24	
					100	34	
					144	35	
$R_{\theta JC}$	CC	D	Thermal resistance, junction-to-case[5]	Single-layer board - 1s	64	11	°C/W
					100	22	
					144	22	
				Four-layer board - 2s2p	64	11	
					100	22	
					144	22	
Ψ_{JB}	CC	D	Junction-to-board thermal characterization parameter, natural convection	Single-layer board - 1s	64	TBD	°C/W
					100	33	
					144	34	
				Four-layer board - 2s2p	64	TBD	
					100	34	
					144	35	
Ψ_{JC}	CC	D	Junction-to-case thermal characterization parameter, natural convection	Single-layer board - 1s	64	TBD	°C/W
					100	9	
					144	10	
				Four-layer board - 2s2p	64	TBD	
					100	9	
					144	10	

[1] Thermal characteristics are based on simulation.

Table 24. I/O weight[1] (continued)

Supply segment			Pad	144/100 LQFP				64 LQFP			
				Weight 5 V		Weight 3.3 V		Weight 5 V		Weight 3.3 V	
144 LQFP	100 LQFP	64 LQFP[2]		SRC[3] = 0	SRC = 1	SRC = 0	SRC = 1	SRC = 0	SRC = 1	SRC = 0	SRC = 1
2	2	2	PB[9]	1%	—	1%	—	1%	—	1%	—
			PB[8]	1%	—	1%	—	1%	—	1%	—
			PB[10]	6%	—	7%	—	6%	—	7%	—
	—	—	PF[0]	6%	—	7%	—	—	—	—	—
	—	—	PF[1]	7%	—	8%	—	—	—	—	—
	—	—	PF[2]	7%	—	8%	—	—	—	—	—
	—	—	PF[3]	7%	—	9%	—	—	—	—	—
	—	—	PF[4]	8%	—	9%	—	—	—	—	—
	—	—	PF[5]	8%	—	10%	—	—	—	—	—
	—	—	PF[6]	8%	—	10%	—	—	—	—	—
	—	—	PF[7]	9%	—	10%	—	—	—	—	—
	2	—	PD[0]	1%	—	1%	—	—	—	—	—
		—	PD[1]	1%	—	1%	—	—	—	—	—
		—	PD[2]	1%	—	1%	—	—	—	—	—
		—	PD[3]	1%	—	1%	—	—	—	—	—
		—	PD[4]	1%	—	1%	—	—	—	—	—
		—	PD[5]	1%	—	1%	—	—	—	—	—
		—	PD[6]	1%	—	1%	—	—	—	—	—
		—	PD[7]	1%	—	1%	—	—	—	—	—
		—	PD[8]	1%	—	1%	—	—	—	—	—
		2	PB[4]	1%	—	1%	—	1%	—	1%	—
			PB[5]	1%	—	1%	—	1%	—	2%	—
			PB[6]	1%	—	1%	—	1%	—	2%	—
			PB[7]	1%	—	1%	—	1%	—	2%	—
		—	PD[9]	1%	—	1%	—	—	—	—	—
		—	PD[10]	1%	—	1%	—	—	—	—	—
		—	PD[11]	1%	—	1%	—	—	—	—	—
		2	PB[11]	11%	—	13%	—	17%	—	21%	—
		—	PD[12]	11%	—	13%	—	—	—	—	—
		2	PB[12]	11%	—	13%	—	18%	—	21%	—
		—	PD[13]	10%	—	12%	—	—	—	—	—

Example 1. No regulator (worst case)

The $|\Delta_{VDD(STDBY)}|$ parameter can be seen as the V_{DD} voltage drop through the ESR resistance of the regulator stability capacitor when the I_{DD_BV} current required to load V_{DD_LV} domain during the standby exit. It is thus possible to define the maximum equivalent resistance $ESR_{STDBY}(MAX)$ of the total capacitance on the V_{DD} supply:

$$ESR_{STDBY}(MAX) = |\Delta_{VDD(STDBY)}|/I_{DD\_BV} = (30\ mV)/(300\ mA) = 0.1\Omega\ ^{1}$$

The dVDD(STDBY)/dt parameter can be seen as the V_{DD} voltage drop at the capacitance pin (excluding ESR drop) while providing the I_{DD_BV} supply required to load V_{DD_LV} domain during the standby exit. It is thus possible to define the minimum equivalent capacitance $C_{STDBY}(MIN)$ of the total capacitance on the V_{DD} supply:

$$C_{STDBY}(MIN) = I_{DD\_BV}/dVDD(STDBY)/dt = (300\ mA)/(15\ mV/\mu s) = 20\ \mu F$$

This configuration is a worst case, with the assumption no regulator is available.

Example 2. Simplified regulator

The regulator should be able to provide significant amount of the current during the standby exit process. For example, in case of an ideal voltage regulator providing 200 mA current, it is possible to recalculate the equivalent $ESR_{STDBY}(MAX)$ and $C_{STDBY}(MIN)$ as follows:

$$ESR_{STDBY}(MAX) = |\Delta_{VDD(STDBY)}|/(I_{DD\_BV} - 200\ mA) = (30\ mV)/(100\ mA) = 0.3\ \Omega$$

$$C_{STDBY}(MIN) = (I_{DD\_BV} - 200\ mA)/dVDD(STDBY)/dt = (300\ mA - 200\ mA)/(15\ mV/\mu s) = 6.7\ \mu F$$

In case optimization is required, $C_{STDBY}(MIN)$ and $ESR_{STDBY}(MAX)$ should be calculated based on the regulator characteristics as well as the board V_{DD} plane characteristics.

3.17.2 Low voltage detector electrical characteristics

The device implements a Power-on Reset (POR) module to ensure correct power-up initialization, as well as four low voltage detectors (LVDs) to monitor the V_{DD} and the V_{DD_LV} voltage while device is supplied:

- POR monitors V_{DD} during the power-up phase to ensure device is maintained in a safe reset state (refer to RGM Destructive Event Status (RGM_DES) Register flag F_POR in device reference manual)
- LVDHV3 monitors V_{DD} to ensure device reset below minimum functional supply (refer to RGM Destructive Event Status (RGM_DES) Register flag F_LVD27 in device reference manual)
- LVDHV5 monitors V_{DD} when application uses device in the 5.0 V ± 10% range (refer to RGM Functional Event Status (RGM_FES) Register flag F_LVD45 in device reference manual)
- LVDLVCOR monitors power domain No. 1 (refer to RGM Destructive Event Status (RGM_DES) Register flag F_LVD12_PD1 in device reference manual
- LVDLVBKP monitors power domain No. 0 (refer to RGM Destructive Event Status (RGM_DES) Register flag F_LVD12_PD0 in device reference manual)

NOTE

When enabled, power domain No. 2 is monitored through LVDLVBKP.

1. Based on typical time for standby exit sequence of 20 µs, ESR(MIN) can actually be considered at ~50 kHz.

Table 32. Flash memory power supply DC electrical characteristics

Symbol		C	Parameter	Conditions[1]	Value			Unit
					Min	Typ	Max	
I_{FLPW}	CC	D	Sum of the current consumption on VDD_HV and VDD_BV	During code flash memory low-power mode	—	—	900	µA
				During data flash memory low-power mode	—	—	900	
I_{FPWD}	CC	D	Sum of the current consumption on VDD_HV and VDD_BV	During code flash memory power-down mode	—	—	150	µA
				During data flash memory power-down mode	—	—	150	

1 V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified

2 This value is only relative to the actual duration of the read cycle

3 f_{CPU} 64 MHz can be achieved only at up to 105 °C

3.19.3 Start-up/Switch-off timings

Table 33. Start-up time/Switch-off time

Symbol		C	Parameter	Conditions[1]	Value			Unit
					Min	Typ	Max	
$T_{FLARSTEXIT}$	CC	T	Delay for Flash module to exit reset mode	Code Flash	—	—	125	µs
		T		Data Flash	—	—	125	
$T_{FLALPEXIT}$	CC	T	Delay for Flash module to exit low-power mode	Code Flash	—	—	0.5	
		T		Data Flash	—	—	0.5	
$T_{FLAPDEXIT}$	CC	T	Delay for Flash module to exit power-down mode	Code Flash	—	—	30	
		T		Data Flash	—	—	30	
$T_{FLALPENTRY}$	CC	T	Delay for Flash module to enter low-power mode	Code Flash	—	—	0.5	
		T		Data Flash	—	—	0.5	
$T_{FLAPDENTRY}$	CC	T	Delay for Flash module to enter power-down mode	Code Flash	—	—	1.5	
		T		Data Flash	—	—	1.5	

1 V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified

3.20 Electromagnetic compatibility (EMC) characteristics

Susceptibility tests are performed on a sample basis during product characterization.

3.20.1 Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Table 41. FMPLL electrical characteristics

Symbol		C	Parameter	Conditions[1]	Value			Unit
					Min	Typ	Max	
f_{PLLIN}	SR	—	FMPLL reference clock[2]	—	4	—	64	MHz
Δ_{PLLIN}	SR	—	FMPLL reference clock duty cycle[2]	—	40	—	60	%
f_{PLLOUT}	CC	D	FMPLL output clock frequency	—	16	—	64	MHz
f_{VCO}[3]	CC	P	VCO frequency without frequency modulation	—	256	—	512	MHz
		C	VCO frequency with frequency modulation	—	245	—	533	
f_{CPU}	SR	—	System clock frequency	—	—	—	64	MHz
f_{FREE}	CC	P	Free-running frequency	—	20	—	150	MHz
t_{LOCK}	CC	P	FMPLL lock time	Stable oscillator (f_{PLLIN} = 16 MHz)	—	40	100	µs
Δt_{STJIT}	CC	—	FMPLL short term jitter[4]	f_{sys} maximum	–4	—	4	%
Δt_{LTJIT}	CC	—	FMPLL long term jitter	f_{PLLIN} = 16 MHz (resonator), f_{PLLCLK} @ 64 MHz, 4000 cycles	—	—	10	ns
I_{PLL}	CC	C	FMPLL consumption	T_A = 25 °C	—	—	4	mA

1 V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified.

2 PLLIN clock retrieved directly from FXOSC clock. Input characteristics are granted when oscillator is used in functional mode. When bypass mode is used, oscillator input clock should verify f_{PLLIN} and Δ_{PLLIN}.

3 Frequency modulation is considered ±4%

4 Short term jitter is measured on the clock rising edge at cycle n and n+4.

3.24 Fast internal RC oscillator (16 MHz) electrical characteristics

The device provides a 16 MHz fast internal RC oscillator. This is used as the default clock at the power-up of the device.

Table 42. Fast internal RC oscillator (16 MHz) electrical characteristics

Symbol		C	Parameter	Conditions[1]	Value			Unit
					Min	Typ	Max	
f_{FIRC}	CC	P	Fast internal RC oscillator high frequency	T_A = 25 °C, trimmed	—	16	—	MHz
	SR	—		—	12		20	
$I_{FIRCRUN}$[2],	CC	T	Fast internal RC oscillator high frequency current in running mode	T_A = 25 °C, trimmed	—	—	200	µA
$I_{FIRCPWD}$	CC	D	Fast internal RC oscillator high frequency current in power down mode	T_A = 125 °C	—	—	10	µA

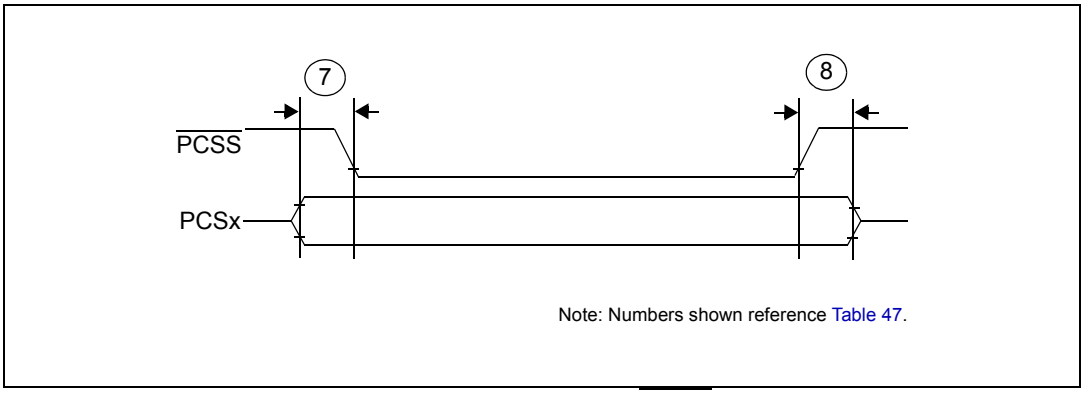

Figure 32. DSPI PCS strobe (PCSS) timing

3.27.3 Nexus characteristics

Table 48. Nexus characteristics

No.	Symbol		C	Parameter	Value			Unit
					Min	Typ	Max	
1	t_{TCYC}	CC	D	TCK cycle time	64	—	—	ns
2	t_{MCYC}	CC	D	MCKO cycle time	32	—	—	ns
3	t_{MDOV}	CC	D	MCKO low to MDO data valid	—	—	8	ns
4	t_{MSEOV}	CC	D	MCKO low to MSEO_b data valid	—	—	8	ns
5	t_{EVTOV}	CC	D	MCKO low to EVTO data valid	—	—	8	ns
10	t_{NTDIS}	CC	D	TDI data setup time	15	—	—	ns
	t_{NTMSS}	CC	D	TMS data setup time	15	—	—	ns
11	t_{NTDIH}	CC	D	TDI data hold time	5	—	—	ns
	t_{NTMSH}	CC	D	TMS data hold time	5	—	—	ns
12	t_{TDOV}	CC	D	TCK low to TDO data valid	35	—	—	ns
13	t_{TDOI}	CC	D	TCK low to TDO data invalid	6	—	—	ns

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NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M–1994.
3. DATUMS A, B AND D TO BE DETERMINED AT DATUM PLANE H.
4. DIMENSIONS TO BE DETERMINED AT SEATING PLANE C.
5. THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED THE UPPER LIMIT BY MORE THAN 0.08 mm AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD SHALL NOT BE LESS THAN 0.07 mm.
6. THIS DIMENSION DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 mm PER SIDE. THIS DIMENSION IS MAXIMUM PLASTIC BODY SIZE DIMENSION INCLUDING MOLD MISMATCH.
7. EXACT SHAPE OF EACH CORNER IS OPTIONAL.
8. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.1 mm AND 0.25 mm FROM THE LEAD TIP.

TITLE: 64LD LQFP, 10 X 10 X 1.4 PKG, 0.5 PITCH, CASE OUTLINE	CASE NUMBER: 840F–02	
	STANDARD: JEDEC MS–026 BCD	
	PACKAGE CODE: 8426	SHEET: 3

Figure 37. 64 LQFP package mechanical drawing (3 of 3)

4.1.3 144 LQFP

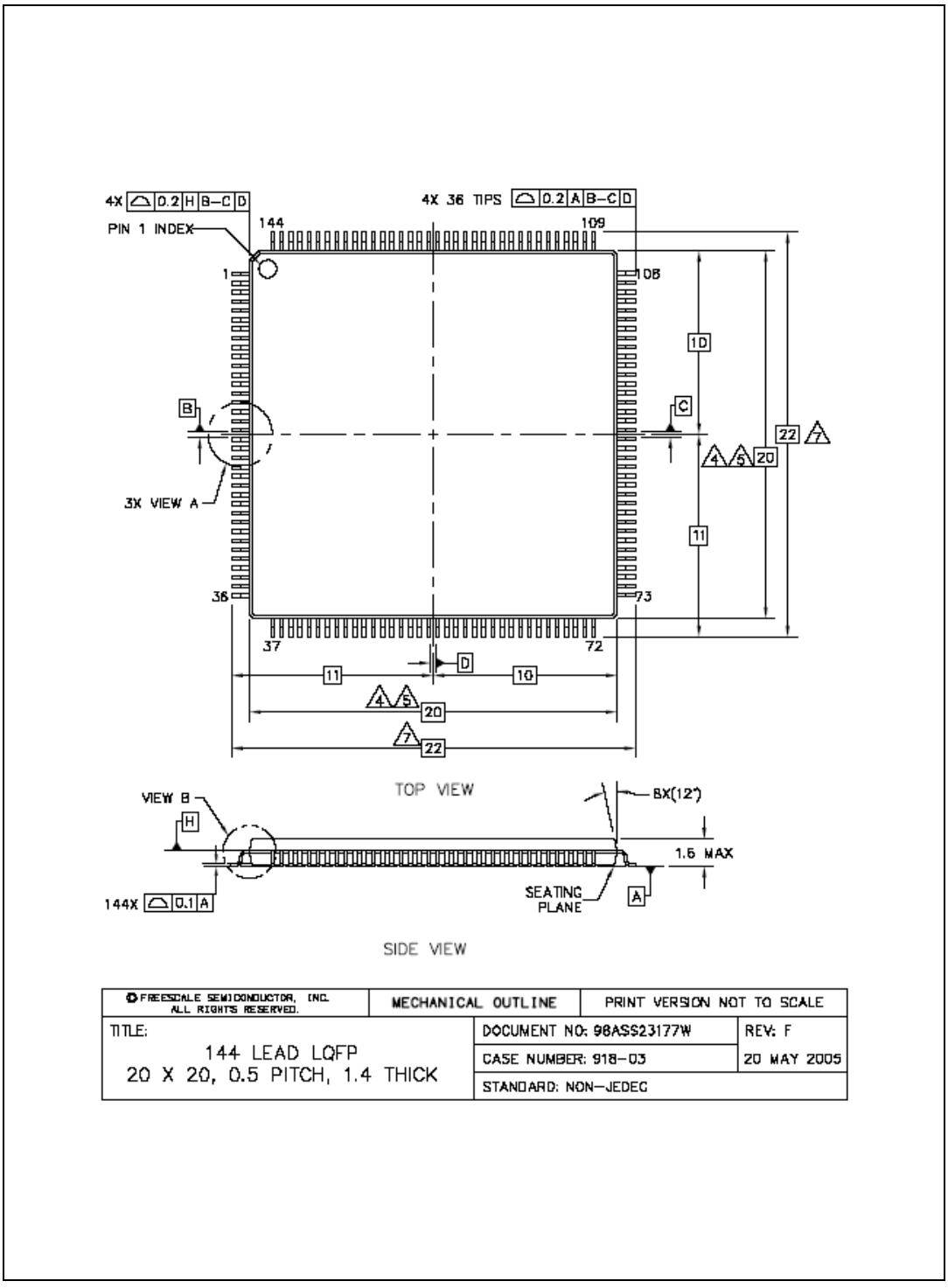

Figure 41. 144 LQFP package mechanical drawing (1 of 2)

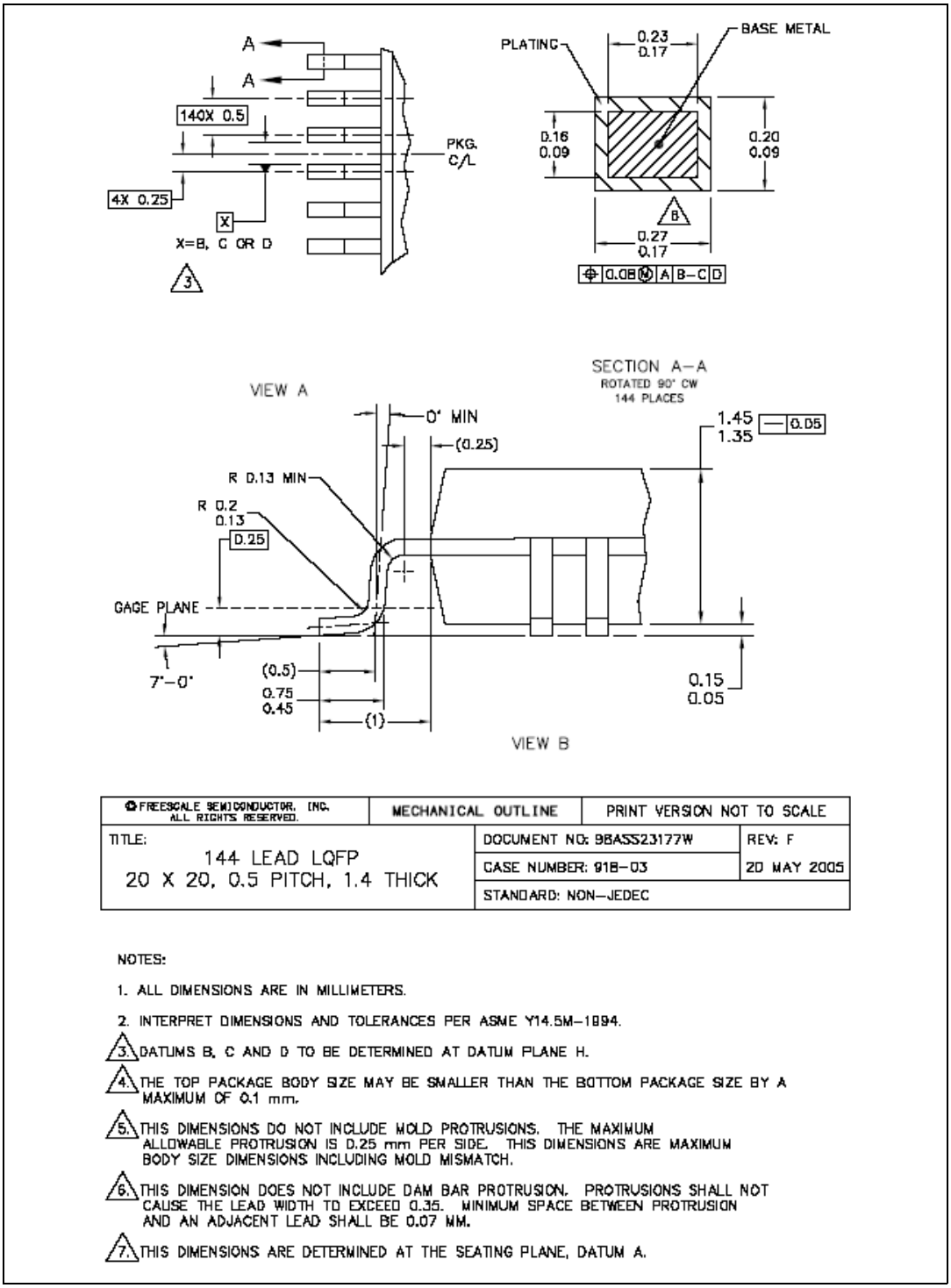

Figure 42. 144 LQFP package mechanical drawing (2 of 2)

Table 50. Revision history (continued)

Revision	Date	Description of Changes
6	15-Mar-2010	In the “Introduction” section, relocated a note. In the “MPC5604B/C device comparison” table, added footnote regarding SCI and CAN. In the “Absolute maximum ratings” table, removed the min value of V_{IN} relative to V_{DD}. In the “Recommended operating conditions (3.3 V)” table: • $T_{A\ C\text{-}Grade\ Part}$, $T_{J\ C\text{-}Grade\ Part}$, $T_{A\ V\text{-}Grade\ Part}$, $T_{J\ V\text{-}Grade\ Part}$, $T_{A\ M\text{-}Grade\ Part}$, $T_{J\ M\text{-}Grade\ Part}$: added new rows. • TV_{DD}: made single row. In the “LQFP thermal characteristics” table, added more rows. Removed “208 MAPBGA thermal characteristics” table. In the “I/O consumption” table: • Removed I_{DYNSEG} row. • Added “I/O weight” table. In the “Voltage regulator electrical characteristics” table: • Updated the values. • Removed $I_{VREGREF}$ and $I_{VREDLVD12}$. • Added a note about I_{DD_BC}. In the “Low voltage monitor electrical characteristics” table: • Updated V_{PORH} values. • Updated $V_{LVDLVCORL}$ value. Entirely updated the “Low voltage power domain electrical characteristics” table. In the “Program and erase specifications” table, inserted T_{eslat} row. Entirely updated the “Flash power supply DC electrical characteristics” table. Entirely updated the “Start-up time/Switch-off time” table. In the “Crystal oscillator and resonator connection scheme” figure, relocated a note. In the “Slow external crystal oscillator (32 kHz) electrical characteristics” table: • Removed g_{mSXOSC} row. • Inserted values of $I_{SXOSCBIAS}$. Entirely updated the “Fast internal RC oscillator (16 MHz) electrical characteristics” table. In the “ADC conversion characteristics” table: updated the description of the conditions of t_{ADC_PU} and t_{ADC_S}. Entirely updated the “DSPI characteristics” table. In the “Orderable part number summary” table, modified some orderable part number. Updated the “Commercial product code structure” figure. Removed the note about the condition from “Flash read access timing” table Removed the notes that assert the values need to be confirmed before validation Exchanged the order of “LQFP 100-pin configuration” and “LQFP 144-pin configuration” Exchanged the order of “LQFP 100-pin package mechanical drawing” and “LQFP 144-pin package mechanical drawing”

Appendix A Abbreviations

Table A-1 lists abbreviations used but not defined elsewhere in this document.

Table A-1. Abbreviations

Abbreviation	Meaning
CMOS	Complementary metal–oxide–semiconductor
CPHA	Clock phase
CPOL	Clock polarity
CS	Peripheral chip select
EVTO	Event out
MCKO	Message clock out
MDO	Message data out
MSEO	Message start/end out
MTFE	Modified timing format enable
SCK	Serial communications clock
SOUT	Serial data out
TBD	To be defined
TCK	Test clock input
TDI	Test data input
TDO	Test data output
TMS	Test mode select

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Japan:
Freescale Semiconductor Japan Ltd. Headquarters
ARCO Tower 15F
1-8-1, Shimo-Meguro, Meguro-ku,
Tokyo 153-0064
Japan
0120 191014 or +81 3 5437 9125
support.japan@freescale.com

Asia/Pacific:
Freescale Semiconductor China Ltd.
Exchange Building 23F
No. 118 Jianguo Road
Chaoyang District
Beijing 100022
China
+86 10 5879 8000
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MPC5604BC
Rev. 11
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